## **Supporting Information**

## An Ion-Conducting SnS-SnS<sub>2</sub> Hybrid Coating for Commercial Activated Carbons Enabling Their Use as High Performance Anodes for Sodium-Ion Batteries

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Scheme S1. Schematic illustration of the preparation process of the AC@SnS-SnS<sub>2</sub>.



Figure S1. SEM images of the oxidized AC.



Figure S2. (a) TEM image and (b-c) HRTEM images of the AC@SnO<sub>2</sub>.



**Figure S3.** TEM images (a-c) and Fast Fourier transform (FFT)-diffraction (d-f) of the SnS $_2$  hybrid nanosheets on the surface of the AC.



**Figure S4.** (a) SEM image and (b) C, (c) S, (d) Sn, (e) O element mappings of the AC@SnS-SnS<sub>2</sub>.



Figure S5. Raman spectra of AC, oxidized AC and AC@SnS-SnS<sub>2</sub>.



**Figure S6.** (a) Typical XPS survey spectra of AC@SnS-SnS<sub>2</sub> and AC@SnO<sub>2</sub>, (b) S 2p, and (c) C 1s XPS spectra of the AC@SnS-SnS<sub>2</sub>.



**Figure S7.** Structural and electrochemical characterization of the oxidized AC. (a) Nitrogen adsorption isotherm with the pore size distribution, (b) XRD pattern, (c) galvanostatic charge-discharge profiles, (d) cyclic performance at a current density of 0.1 A  $g^{-1}$ , (e) rate performance, and (f) Nyquist plots of the oxidized AC.



**Figure S8.** Structural and electrochemical characterization of the AC@SnO<sub>2</sub>. (a) Nitrogen adsorption isotherm with the inserted pore size distribution, (b) XRD pattern, (c) galvanostatic charge-discharge profiles, and (d) Nyquist plots of the AC@SnO<sub>2</sub>.

	Cnts 4.0	с к – С -	
15 kV 20kX	2.0	K - Sn S Sn S	10 15 20 keV 5 - 40.955= 41,988 cnt
Element	Intensity (c/s)	Atomic (%)	Mass (%)
С	360.84	80.63	61.89
0	34.76	13.46	13.76
S	103.92	3.70	7.58
Sn	37.35	2.21	16.77

**Figure S9.** EDS spectrum of the AC@SnS-SnS<sub>2</sub>. Wide area EDS analysis indicated the existing of 2.21% Sn and 3.697% S (atomic ratio), so the corresponding ratio of SnS<sub>2</sub> is 1.497% and SnS is 0.703%, and the Sn<sup>4+</sup>/Sn<sup>2+</sup> mole ratio is about 2.13, suggesting the formation of the SnS-SnS<sub>2</sub> hybrids. (The Sn<sup>4+</sup>/Sn<sup>2+</sup> ratio measured with XPS is estimated to be around 2.15).



**Figure S10.** TGA curves of AC@SnS-SnS<sub>2</sub>, AC@SnO<sub>2</sub>, and AC. The AC has 2.72 wt% impurities which can't be burned before treated by HNO<sub>3</sub>. Since the Sn<sup>4+</sup>/Sn<sup>2+</sup> ratio is about 2.1, the amounts of SnS<sub>2</sub> and SnS in the AC@SnS-SnS<sub>2</sub> are about 8.47 wt% and 3.34 wt%.



**Figure S11.** Galvanostatic charge-discharge curves of (a) AC and (b) oxidized AC at a current density of  $0.1 \text{ A g}^{-1}$ .



**Figure S12**. The SEM images of the AC@SnS-SnS<sub>2</sub> electrode (a and b) before and (c and d) after 100 cycles charge/discharge at a current density of 0.3 A  $g^{-1}$ .



Figure S13. XPS results of cycled AC@SnS-SnS<sub>2</sub> electrode. (a) XPS survey spectra; (b) atomic contents; (c) Sn 3d; (d) Na 1s; (e) O 1s and (f) C 1s profiles



Figure S14. Nyquist plots of AC@SnS-SnS<sub>2</sub> before and after 10 cycles

**Table S1.** The comparison of the sodium storage performance of the AC@SnS-SnS<sub>2</sub> vs. other coatings on porous carbon materials.

Materials	ICE (%)	Rate performance	Reference
CNTs/CFP@TiO2	43.6	128.6 mA h g <sup>-1</sup> at 2 A g <sup>-1</sup>	[1]
HPC@G	/	250 mA h g <sup>-1</sup> at 1 A g <sup>-1</sup>	[2]
CNT@SnO <sub>2</sub> @G	43	97 mA h g <sup>-1</sup> at 1 A g <sup>-1</sup>	[3]
Porous carbon/TiO <sub>2</sub>	/	120 mA h g <sup>-1</sup> at 0.11 A g <sup>-1</sup>	[4]
NC/TiO <sub>2</sub>	37.3	104 mA h g <sup>-1</sup> at 3.3 A g <sup>-1</sup>	[5]
SnS@rGO	42	240 mA h g <sup>-1</sup> at 0.4 A g <sup>-1</sup>	[6]
SnS-C	~60	450 mA h g <sup>-1</sup> at 0.80 A g <sup>-1</sup>	[7]
$SnS_2/C$	~75	80 mA h g <sup>-1</sup> at 2 A g <sup>-1</sup>	[8]
SnS <sub>2</sub> /rGO	~55	530 mA h g <sup>-1</sup> at 2 A g <sup>-1</sup>	[9]
SnS <sub>2</sub> /graphene	~50	337 mA h g <sup>-1</sup> at 12.8 A g <sup>-1</sup>	[10]
AC@SnS-SnS <sub>2</sub>	68.6	110 mA h g <sup>-1</sup> at 5 A g <sup>-1</sup>	This Work



Figure S15. CV curves of (a) AC and (b) oxidized AC at a scan rate of 0.1 mV s<sup>-1</sup>.



**Figure S16.** CV curves at various scan rates from 0.1 mV s<sup>-1</sup> to 2 mV s<sup>-1</sup> of the (a) AC, (b) oxidized AC and (c) AC@SnS-SnS<sub>2</sub>; Determination of the *b* values for various selected conditions for (d) AC, (e) oxidized AC and (f) AC@SnS-SnS<sub>2</sub>.

	•	<b>e</b> 1	*
Samples	$R_{s}/\Omega$	$R_{ct}/\Omega$	$D/cm^{-2}s^{-1}$
AC@SnS-SnS2	4.7	136.1	7.67×10 <sup>-13</sup>
AC@SnO2	5.2	323.6	6.58×10 <sup>-13</sup>
AC	4.9	342.5	4.39×10 <sup>-13</sup>

Table S2. Parameters of equivalent circuit modeling of EIS spectra of different samples.



Figure S17. TGA curves of AC@SnS-SnS<sub>2</sub>- I and AC@SnS-SnS<sub>2</sub>- II



Figure S18. EDS results of the AC@SnS-SnS<sub>2</sub>- I and AC@SnS-SnS<sub>2</sub>- II



Figure S19. Structure and electrochemical characterization of the AC with different contents of SnS-SnS<sub>2</sub> hybrid. (a) Nitrogen adsorption isotherms; (b) Pore size distributions; and Galvanostatic chargedischarge profiles of AC@SnS-SnS<sub>2</sub>- I (c) and AC@SnS-SnS<sub>2</sub>- II (d) at a current density of 0.1 A g<sup>-1</sup>; (e) Cycling performance of them at 0.1 A g<sup>-1</sup>.



Figure S20. SEM images of (a) AC@SnS<sub>2</sub> and (b) AC@SnS



**Figure S21.** (a) XRD patterns, (b) Raman spectra, (c) Sn 3d XPS spectra, (d) TGA curves, (e) N<sub>2</sub> adsorption isotherms, and (f) pore size distributions of AC@SnS<sub>2</sub> and AC@SnS.



**Figure S22.** (a and b) Galvanostatic charge-discharge profiles for selected cycles of  $AC@SnS_2$  and AC@SnS at a current density of 0.1 A g<sup>-1</sup>; (c and d) CV curves of the first four cycles of AC@SnS<sub>2</sub> and AC@SnS at a scan rate of 0.1 mV s<sup>-1</sup>; (e) Cyclic performance of AC@SnS<sub>2</sub> and AC@SnS at a current density of 0.1 A g<sup>-1</sup>; (f) Rate performance of AC@SnS<sub>2</sub> and AC@SnS at a current density of 0.05 A g<sup>-1</sup> to 5 A g<sup>-1</sup>; (g) Nyquist plots of AC@SnS<sub>2</sub> and AC@SnS after the first cycle.

**Results for the other two kinds of AC:** 



Figure S23. TEM images of the AC-2@SnS-SnS<sub>2</sub>



**Figure S24.** Galvanostatic charge-discharge curves of (a and b) the other two kinds of AC, (c and d) the correlated oxidized ACs at a current density of  $0.1 \text{ A g}^{-1}$ .



**Figure S25.** (a and b) Cyclic performances at 0.1 A  $g^{-1}$  and (c and d) rate performances of the other two kinds of AC, the correlated oxidized ACs and the correlated AC@SnS-SnS<sub>2</sub>s.

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